

Data Sheet December 29, 2004 FN9077.6

# 80V/1.25A Peak, Medium Frequency, Low Cost, Half-Bridge Driver

The ISL6700 is an 80V/1.25A peak, medium frequency, low cost, half-bridge driver IC available in 8-lead SOIC and 12-lead QFN plastic packages. The low-side and high-side gate drivers are independently controlled and matched to 25ns. This gives the user maximum flexibility in dead-time selection and driver protocol. Undervoltage protection on both the low-side and high-side supplies force the outputs low. Non-latching, level-shift translation is used to control the upper drive circuit. Unlike some competitors, the high-side output returns to its correct state after a momentary undervoltage of the high-side supply.

### **Ordering Information**

| PART<br>NUMBER           | TEMP. RANGE<br>(°C) | PACKAGE                    | PKG. DWG. # |  |
|--------------------------|---------------------|----------------------------|-------------|--|
| ISL6700IB                | -40 to 125          | 8 Ld SOIC                  | M8.15       |  |
| ISL6700IBZ<br>(See Note) | -40 to 125          | 8 Ld SOIC<br>(Pb-free)     | M8.15       |  |
| ISL6700IR                | -40 to 125          | 12 Ld 4x4 QFN              | L12.4x4     |  |
| ISL6700IRZ<br>(See Note) | -40 to 125          | 12 Ld 4x4 QFN<br>(Pb-free) | L12.4x4     |  |

Add "-T" suffix to part number for tape and reel packaging.

NOTE: Intersil Pb-free products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

### **Pinouts**

# TOP VIEW V<sub>DD</sub> 1 8 HB HI 2 7 HO LI 3 6 HS V<sub>SS</sub> 4 5 LO

ISL6700IB (SOIC)

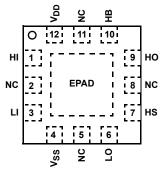
### Features

- Drives 2 N-Channel MOSFETs in Half-Bridge Configuration
- Space Saving SO8 and Low R<sub>C-S</sub> QFN Packages
- · Phase Supply Max Voltage to 80VDC
- Bootstrap Supply Max Voltage to 96VDC
- · Drives 1000pF Load with Rise and Fall Times Typ. 15ns
- · TTL/CMOS Compatible Input Thresholds
- Independent Inputs for Non-Half-Bridge Topologies
- · No Start-Up Problems
- · Low Power Consumption
- · Wide Supply Range
- · Supply Undervoltage Protection
- QFN Package
  - Compliant to JEDEC PUB95 MO-220 QFN
  - Quad Flat No Leads Package Outline
- Pb-Free Available (RoHS Compliant)

### **Applications**

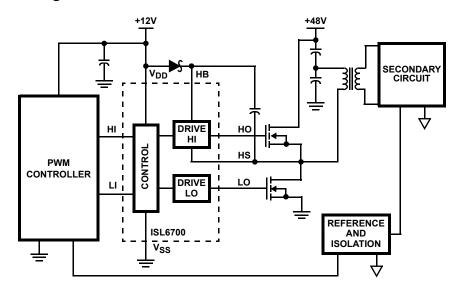
- · Telecom/Datacom Power Supplies
- · Half-Bridge Converters
- · Two-Switch Forward Converters
- Active Clamp Forward Converters



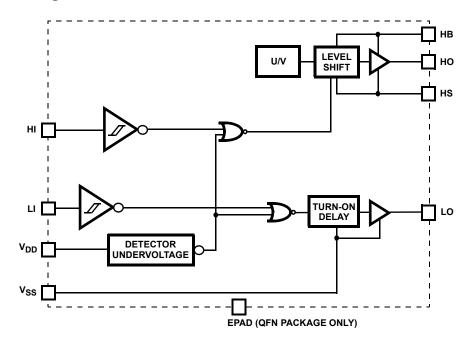


NOTE: EPAD = Exposed PAD.

# Application Block Diagram



# Functional Block Diagram



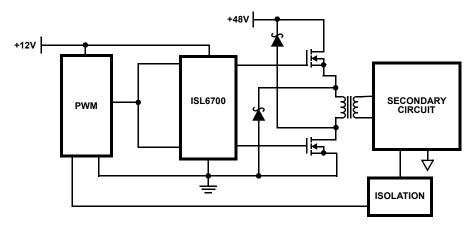


FIGURE 1. TWO-SWITCH FORWARD CONVERTER

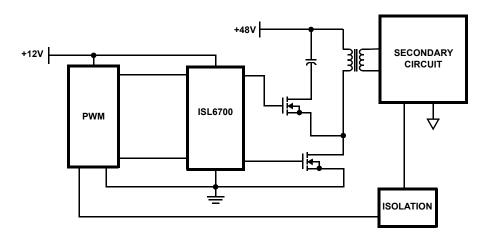


FIGURE 2. FORWARD CONVERTER WITH AN ACTIVE CLAMP

### **Absolute Maximum Ratings**

| Supply Voltage, V <sub>DD</sub> (Note 1) | 0.3V to 16V                                     |
|--|---|
| LI and HI Voltages (Note 1)              | 0.3V to V <sub>DD</sub> +0.3V                   |
| Voltage on HS (Note 1)                   | 0V to 80V                                       |
| Voltage on HB (Note 1)                   | $V_{HS}$ -0.3V to $V_{HS}$ + $V_{DD}$           |
| Voltage on LO (Note 1)                   | . V <sub>SS</sub> -0.3 to V <sub>DD</sub> +0.3V |
| Voltage on HO (Note 1)                   | $V_{HS}$ -0.3V to $V_{HB}$ +0.3V                |
| Phase Slew Rate                          |   |

### **Maximum Recommended Operating Conditions**

| Supply Voltage, V <sub>DD</sub> |   |
|---------------------------------|---|
| Voltage on HS                   | 0V to 75V   |
| Voltage on HS (Note 2)          | (Repetitive Transient) -1V to 80V                         |
| Voltage on HB                   | V <sub>HS</sub> +7.5V to V <sub>HS</sub> +V <sub>DD</sub> |

### **Thermal Information**

| Thermal Resistance (Typical)              | θ <sub>JA</sub> (°C/W) | θ <sub>JC</sub> (°C/W) |
|---|------------------------|------------------------|
| SOIC (Note 3)                             | 95                     | N/A                    |
| QFN (Note 4)                              | 49                     | 7                      |
| Max Power Dissipation at 25°C in Free Air | (SOIC, Note            | 3). 1.316W             |
| Max Power Dissipation at 25°C in Free Air | (QFN, Note             | 4)2.976W               |
| Maximum Storage Temperature Range         | 65°                    | °C to +150°C           |
| Maximum Junction Temperature Range .      | 40°                    | °C to +150°C           |
| Maximum Lead Temperature (Soldering 1     | 0s)                    | +300°C                 |
| (SOIC - Lead Tips Only)                   |                        |                        |
| For Recommended soldering conditions s    | ee Tech Brief          | TB389.                 |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the recommended operating conditions of this specification is not implied.

### NOTES:

- 1. All voltages referenced to  $V_{\mbox{\footnotesize SS}}$  unless otherwise specified.
- 2. Based on V<sub>DD</sub>=15V. The magnitude of the allowable negative transient on the HS pin is a function of the V<sub>DD</sub> supply voltage. V<sub>HS</sub><15.6V-V<sub>DD</sub>+V<sub>F</sub>, where V<sub>HS</sub> is the magnitude of the allowable negative transient and V<sub>F</sub> is the forward voltage drop of the bootstrap diode.
- 3.  $\theta_{JA}$  is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.
- 4. θ<sub>JA</sub> is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. θ<sub>JC</sub>, the "case temp" is measured at the center of the exposed metal pad on the package underside. See Tech Brief TB379.

### **Electrical Specifications** $V_{DD} = V_{HB} = 12V$ , $V_{SS} = V_{HS} = 0V$ , No Load on LO or HO, Unless Otherwise Specified

|  |                    |   | 1           | T <sub>J</sub> = 25°C |      | T <sub>J</sub> =-40°C TO<br>125°C |       |    |
|--|--------------------|---|-------------|-----------------------|------|-----------------------------------|-------|----|
| PARAMETERS                                     | SYMBOL             | TEST CONDITIONS                                 | MIN TYP MAX |                       | MIN  | MAX                               | UNITS |    |
| SUPPLY CURRENTS & UNDERVOLTA                   | GE PROTEC          | TION  |             |                       |      |                                   |       |    |
| V <sub>DD</sub> Quiescent Current              | I <sub>DD</sub>    | LI = 0 or V <sub>DD</sub>                       | -           | 1.9                   | 2.2  | -                                 | 2.4   | mA |
| V <sub>DD</sub> Operating Current              | I <sub>DDO</sub>   | f = 50kHz                                       | -           | 2.0                   | 2.2  | -                                 | 2.5   | mA |
| V <sub>DD</sub> Operating Current              | I <sub>DDO</sub>   | f = 500kHz                                      | -           | 2.5                   | 3.0  | -                                 | 4.0   | mA |
| HB Off Quiescent Current                       | I <sub>HBL</sub>   | HI = 0  | -           | 1.25                  | 1.5  | -                                 | 1.8   | mA |
| HB On Quiescent Current                        | I <sub>HBH</sub>   | HI = V <sub>DD</sub>                            | -           | 170                   | 240  | -                                 | 250   | μА |
| HB Operating Current                           | I <sub>HBO</sub>   | f = 50kHz, C <sub>L</sub> = 1000pF              | -           | 1.45                  | 1.8  | -                                 | 2.0   | mA |
| HB Operating Current                           | I <sub>HBO</sub>   | f = 500kHz, C <sub>L</sub> = 1000pF             | -           | 2.4                   | 2.8  | -                                 | 3.0   | mA |
| HS Leakage Current                             | IHLK               | V <sub>HS</sub> = 80V<br>V <sub>HB</sub> = 96V  | -           | -                     | 1    | -                                 | 1     | μА |
| V <sub>DD</sub> Rising Undervoltage Threshold  | V <sub>DDUV+</sub> |   | 6.8         | 7.6                   | 8.25 | 6.5                               | 8.5   | V  |
| V <sub>DD</sub> Falling Undervoltage Threshold | V <sub>DDUV-</sub> |   | 6.5         | 7.1                   | 7.8  | 6.25                              | 8.1   | V  |
| Undervoltage Hysteresis                        | UVHYS              |   | 0.17        | 0.45                  | 0.75 | 0.15                              | 0.90  | V  |
| HB Undervoltage Threshold                      | VHBUV              | Referenced to HS                                | 4.8         | 5.3                   | 6.5  | 4.0                               | 7.5   | V  |
| INPUT PINS: LI and HI                          |                    |   |             |                       |      |                                   |       |    |
| Low Level Input Voltage                        | V <sub>IL</sub>    | Full Operating Conditions                       | 0.8         | 1.6                   | -    | 8.0                               | -     | V  |
| High Level Input Voltage                       | V <sub>IH</sub>    | Full Operating Conditions                       | -           | 1.7                   | 2.2  | -                                 | 2.2   | V  |
| Input Voltage Hysteresis                       |                    |   | -           | 100                   | -    | -                                 | -     | mV |
| Low Level Input Current                        | I <sub>IL</sub>    | V <sub>IN</sub> = 0V, Full Operating Conditions | -70         | -60                   | -30  | -80                               | -30   | μА |
| High Level Input Current                       | lін                | V <sub>IN</sub> = 5V, Full Operating Conditions | 30          | 115                   | 130  | 30                                | 145   | μА |

FN9077.6 intersil December 29, 2004

# $\textbf{Electrical Specifications} \qquad \textit{V}_{DD} = \textit{V}_{HB} = \textit{12V}, \ \textit{V}_{SS} = \textit{V}_{HS} = \textit{0V}, \ \textit{No Load on LO or HO}, \ \textit{Unless Otherwise Specified (Continued)}$

|                                  |                     |                        | T <sub>J</sub> = 25°C |     | T <sub>J</sub> =-40°C TO<br>125°C |     |     |       |
|----------------------------------|---------------------|------------------------|-----------------------|-----|-----------------------------------|-----|-----|-------|
| PARAMETERS                       | SYMBOL              | TEST CONDITIONS        | MIN                   | TYP | MAX                               | MIN | MAX | UNITS |
| GATE DRIVER OUTPUT PINS: LO & HO |                     |                        |                       |     |                                   |     |     |       |
| Low Level Output Voltage         | V <sub>OL</sub>     | I <sub>OUT</sub> = 0A  | -                     | -   | 0.1                               | -   | 0.1 | V     |
| High Level Output Voltage        | $V_{DD}$ - $V_{OH}$ | I <sub>OUT</sub> = 0A  | -                     | -   | 0.1                               | -   | 0.1 | V     |
| Peak Pullup Current              | I <sub>O</sub> +    | V <sub>OUT</sub> = 0V  | -                     | 1.4 | -                                 | -   | -   | Α     |
| Peak Pulldown Current            | l <sub>O</sub> -    | V <sub>OUT</sub> = 12V | -                     | 1.3 | -                                 | 1   | -   | Α     |

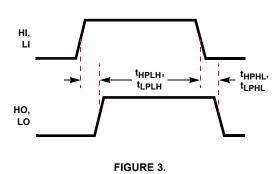
# $\textbf{Switching Specifications} \quad \textit{V}_{DD} = \textit{V}_{HB} = 12 \textit{V}, \textit{V}_{SS} = \textit{V}_{HS} = 0 \textit{V}, \textit{No Load on LO or HO}, \textit{Unless Otherwise Specified}$

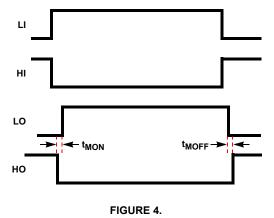
|  |                   | TEST                           | T <sub>J</sub> = 25°C |     | T <sub>J</sub> = -40°C<br>TO 125°C |     |     |       |
|--|-------------------|--------------------------------|-----------------------|-----|------------------------------------|-----|-----|-------|
| PARAMETERS   | SYMBOL            | CONDITIONS                     | MIN                   | TYP | MAX                                | MIN | MAX | UNITS |
| Lower Turn-off Propagation Delay<br>(LI Falling to LO Falling) | t <sub>LPHL</sub> |                                | -                     | 45  | 50                                 | -   | 65  | ns    |
| Upper Turn-off Propagation Delay (HI Falling to HO Falling)    | t <sub>HPHL</sub> |                                | -                     | 60  | 75                                 | -   | 90  | ns    |
| Lower Turn-on Propagation Delay (LI Rising to LO Rising)       | t <sub>LPLH</sub> |                                | -                     | 75  | 82                                 | -   | 95  | ns    |
| Upper Turn-on Propagation Delay (HI Rising to HO Rising)       | t <sub>HPLH</sub> |                                | -                     | 70  | 75                                 | -   | 95  | ns    |
| Deadtime, (t <sub>HPLH</sub> - t <sub>LPHL</sub> )             | DHt <sub>ON</sub> | LI, HI switched simultaneously | 0                     | 24  | -                                  | 0   | -   | ns    |
| Deadtime, (t <sub>LPLH</sub> - t <sub>HPHL</sub> )             | DLt <sub>ON</sub> |                                | 0                     | 17  | -                                  | 0   | -   | ns    |
| Rise Time  | t <sub>R</sub>    |                                | -                     | 5   | 20                                 | -   | 25  | ns    |
| Fall Time  | t <sub>F</sub>    |                                | -                     | 5   | 20                                 | -   | 25  | ns    |
| Delay Matching: Lower Turn-On and Upper Turn-Off               | t <sub>MON</sub>  |                                | -                     | 8   | 20                                 | -   | 25  | ns    |
| Delay Matching: Lower Turn-Off and Upper Turn-On               | t <sub>MOFF</sub> |                                | -                     | -15 | 25                                 | -   | 30  | ns    |

# Pin Descriptions

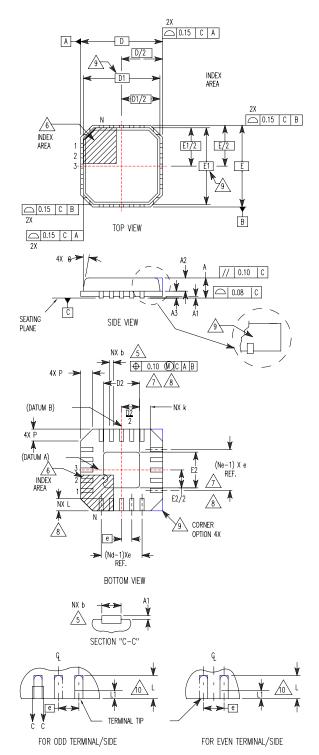
| SYMBOL          | DESCRIPTION   |
|-----------------|---|
| $V_{DD}$        | Positive supply to control logic and lower gate drivers. De-couple this pin to V <sub>SS</sub> . Connect anode of bootstrap diode to this pin.                            |
| HI              | Logic level input that controls the HO output.  |
| LI              | Logic level input that controls the LO output.  |
| V <sub>SS</sub> | Chip negative supply, generally will be ground.   |
| LO              | Low-side output. Connect to gate of low-side power MOSFET.  |
| HS              | High-side source connection. Connect to source of high-side power MOSFET. Connect negative side of bootstrap capacitor to this pin.                                       |
| НО              | High-side output. Connect to gate of high-side power MOSFET.  |
| НВ              | High-side bootstrap supply. External bootstrap diode and capacitor are required. Connect cathode of bootstrap diode and positive side of bootstrap capacitor to this pin. |
| EPAD            | Exposed pad. Connect to ground or float. The EPAD is electrically isolated from all other pins.   |

# Timing Diagrams





## Quad Flat No-Lead Plastic Package (QFN) Micro Lead Frame Plastic Package (MLFP)



L12.4x4

12 LEAD QUAD FLAT NO-LEAD PLASTIC PACKAGE
(COMPLIANT TO JEDEC MO-220-VGGC ISSUE C)

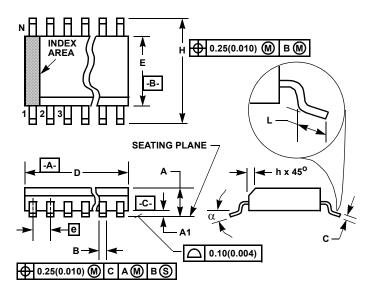
| SYMBOL | MIN  | NOMINAL  | MAX  | NOTES |  |  |
|--------|------|----------|------|-------|--|--|
| А      | 0.80 | 0.90     | 1.00 | -     |  |  |
| A1     | -    | -        | 0.05 | -     |  |  |
| A2     | -    | -        | 1.00 | 9     |  |  |
| A3     |      | 0.20 REF |      | 9     |  |  |
| b      | 0.23 | 0.28     | 0.38 | 5, 8  |  |  |
| D      |      | 4.00 BSC |      | -     |  |  |
| D1     |      | 3.75 BSC |      | 9     |  |  |
| D2     | 1.95 | 2.10     | 2.25 | 7, 8  |  |  |
| Е      |      | 4.00 BSC |      |       |  |  |
| E1     |      | 3.75 BSC |      |       |  |  |
| E2     | 1.95 | 2.10     | 2.25 | 7, 8  |  |  |
| е      |      | 0.80 BSC |      | -     |  |  |
| k      | 0.25 | -        | -    | -     |  |  |
| L      | 0.35 | 0.60     | 0.75 | 8     |  |  |
| L1     | -    | - 0.15   |      | 10    |  |  |
| N      |      | 2        |      |       |  |  |
| Nd     |      | 3        |      |       |  |  |
| Ne     |      | 3        |      |       |  |  |
| Р      | -    | -        | 0.60 | 9     |  |  |
| θ      | -    | -        | 12   | 9     |  |  |

Rev. 1 5/03

### NOTES:

- 1. Dimensioning and tolerancing conform to ASME Y14.5-1994.
- 2. N is the number of terminals.
- 3. Nd and Ne refer to the number of terminals on each D and E.
- 4. All dimensions are in millimeters. Angles are in degrees.
- 5. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
- The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.
- 7. Dimensions D2 and E2 are for the exposed pads which provide improved electrical and thermal performance.
- 8. Nominal dimensions are provided to assist with PCB Land Pattern Design efforts, see Intersil Technical Brief TB389.
- Features and dimensions A2, A3, D1, E1, P & 0 are present when Anvil singulation method is used and not present for saw singulation.
- Depending on the method of lead termination at the edge of the package, a maximum 0.15mm pull back (L1) maybe present. L minus L1 to be equal to or greater than 0.3mm.

### Small Outline Plastic Packages (SOIC)



### NOTES:

- Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side
- 5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
- Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

M8.15 (JEDEC MS-012-AA ISSUE C)
8 LEAD NARROW BODY SMALL OUTLINE PLASTIC
PACKAGE

|        | INCHES |                | MILLIM |                |       |
|--------|--------|----------------|--------|----------------|-------|
| SYMBOL | MIN    | MAX            | MIN    | MAX            | NOTES |
| Α      | 0.0532 | 0.0688         | 1.35   | 1.75           | -     |
| A1     | 0.0040 | 0.0098         | 0.10   | 0.25           | -     |
| В      | 0.013  | 0.020          | 0.33   | 0.51           | 9     |
| С      | 0.0075 | 0.0098         | 0.19   | 0.25           | -     |
| D      | 0.1890 | 0.1968         | 4.80   | 5.00           | 3     |
| Е      | 0.1497 | 0.1574         | 3.80   | 4.00           | 4     |
| е      | 0.050  | 0.050 BSC      |        | BSC            | -     |
| Н      | 0.2284 | 0.2440         | 5.80   | 6.20           | -     |
| h      | 0.0099 | 0.0196         | 0.25   | 0.50           | 5     |
| L      | 0.016  | 0.050          | 0.40   | 1.27           | 6     |
| N      | 8      | 3              | 8      |                | 7     |
| α      | 0°     | 8 <sup>0</sup> | 0°     | 8 <sup>0</sup> | -     |

Rev. 0 12/93

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